HCPL-520x, HCPL-523x, HCPL-623x, HCPL-625x, 5962-88768 and 5962-88769



Hermetically Sealed Low IF, Wide VCC, Logic Gate Optocouplers

Data Sheet

Description

These units are single, dual and quad channel, hermetically sealed optocouplers. The products are capable of operation and storage over the full military temperature range and can be purchased as either standard product or with full MIL-PRF-38534 Class Level H or K testing or from the appropriate DLA Drawing. All devices are manufactured and tested on a MIL-PRF-38534 certified line and are included in the DLA Qualified Manufacturers List QML-38534 for Hybrid Microcircuits.

Each channel contains an AlGaAs light emitting diode which is optically coupled to an integrated high gain photon detector. The detector has a threshold with hysteresis which provides differential mode noise immunity and eliminates the potential for output signal chatter. The detector in the single channel units has a tri-state output stage which allows for direct connection to data buses. The output is noninverting. The detector IC has an internal shield that provides a guaranteed common mode transient immunity of up to 10,000 V/µs. Improved power supply rejection eliminates the need for special power supply bypass precautions.

Features

- Dual Marked with Device Part Number and DLA Standard Microcircuit Drawing
- Manufactured and Tested on a MIL-PRF-38534 Certified Line
- QML-38534, Class H and K
- Four Hermetically Sealed Package Configurations
- Performance Guaranteed over -55°C to +125°C
- Wide V_{CC} Range (4.5 to 20 V)
- 350 ns Maximum Propagation Delay
- CMR: > 10,000 V/μs Typical
- 1500 Vdc Withstand Test Voltage
- Three State Output Available
- High Radiation Immunity
- HCPL-2200/31 Function Compatibility
- Reliability Data Available
- Compatible with LSTTL, TTL, and CMOS Logic

Applications

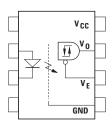
- Military and Space
- High Reliability Systems
- Transportation and Life Critical Systems
- High Speed Line Receiver
- Isolated Bus Driver (Single Channel)
- Pulse Transformer Replacement
- Ground Loop Elimination
- Harsh Industrial Environments
- Computer-Peripheral Interfaces

Note: A 0.1 μF bypass capacitor must be connected between V_{CC} and GND pins.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Functional Diagram

Multiple Channel Devices Available



Package styles for these parts are 8 pin DIP through hole (case outline P), 16 pin DIP flat pack (case outline F), and leadless ceramic chip carrier (case outline 2). Devices may be purchased with a variety of lead bend and plating options, see Selection Guide Table for details. Standard Microcircuit Drawing (SMD) parts are available for each package and lead style.

Because the same electrical die (emitters and detectors) are used for each channel of each device listed in this data sheet, absolute maximum ratings, recommended operating conditions, electrical specifications, and performance characteristics shown in the figures are identical for all parts. Occasional exceptions exist due to package variations and limitations and are as noted. Additionally, the same package assembly processes and materials are used in all devices. These similarities give justification for the use of data obtained from one part to represent other part's performance for die related reliability and certain limited radiation test results.

Truth Tables

(Positive Logic)

Multichannel Devices				
Input	Output			
On (H)	Н			
Off (L)	L			

Single Channel Devices							
Input Enable Output							
On (H)	Н	Z					
Off (L)	Н	Z					
On (H)	L	Н					
Off (L)	L	L					

Functional Diagrams

8 Pin DIP	8 Pin DIP	16 Pin Flat Pack	20 Pad LCCC
Through Hole	Through Hole	Unformed Leads	Surface Mount
1 Channel	2 Channels	4 Channels	2 Channels
1 V _{CC} 8 2 V _C 7 3 V _E 6 4 GND 5	1 V _{CC} 8 2 V _{OC} 6 4 GND 5	16 2 V _{CC} 15 3 V _{CC} 15 10 V _{O1} 14 4 11 V _{O2} 13 5 11 V _{O3} 12 11 V _{O4} 11 7 GND 10 8	19 V _{CC2} 13 12 2 3 V _{CC1} 10 7 8

Note: Multichannel DIP and flat pack devices have common V_{CC} and ground. Single channel DIP has an enable pin 6. LCCC (leadless ceramic chip carrier) package has isolated channels with separate V_{CC} and ground connections.

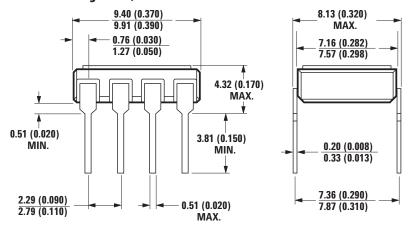
Selection Guide—Package Styles and Lead Configuration Options

Package	8 Pin DIP	8 Pin DIP	16 Pin Flat Pack	20 Pad LCCC
Lead Style	Through Hole	Through Hole	Unformed Leads	Surface Mount
Channels	1	2	4	2
Common Channel Wiring	None	V _{CC} GND	V _{CC} GND	None
Avago Technologies' Part Numbers a	and Options			
Commercial	HCPL-5200	HCPL-5230	HCPL-6250	HCPL-6230
MIL-PRF-38534 Class H	HCPL-5201	HCPL-5231	HCPL-6251	HCPL-6231
MIL-PRF-38534 Class K	HCPL-520K	HCPL-523K	HCPL-625K	HCPL-623K
Standard Lead Finish	Gold Plate	Gold Plate	Gold Plate	Solder Pads *
Solder Dipped*	Option 200	Option 200		
Butt Joint/Gold Plate	Option 100	Option 100		
Gull Wing/Soldered*	Option 300	Option 300		
Class H SMD Part Number	,			
Prescript for all below	5962-	5962-	5962-	5962-
Gold Plate	8876801PC	8876901PC	8876903FC	
Solder Dipped*	8876801PA	8876901PA		88769022A
Butt Joint/Gold Plate	8876801YC	8876901YC		
Butt Joint/Soldered*	8876801YA	8876901YA		
Gull Wing/Soldered*	8876801XA	8876901XA		
Class K SMD Part Number	,			
Prescript for all below	5962-	5962-	5962-	5962-
Gold Plate	8876802KPC	8876904KPC	8876906KFC	
Solder Dipped*	8876802KPA	8876904KPA		8876905K2A
Butt Joint/Gold Plate	8876802KYC	8876904KYC		
Butt Joint/Soldered*	8876802KYA	8876904KYA		
Gull Wing/Soldered*	8876802KXA	8876904KXA		

^{*} Solder contains lead

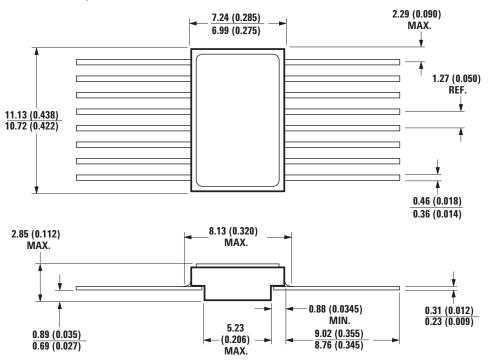
Outline Drawings

8 Pin DIP Through Hole, 1 and 2 Channel



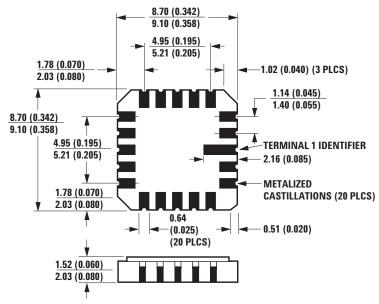
NOTE: DIMENSIONS IN MILLIMETERS (INCHES).

16 Pin Flat Pack, 4 Channels



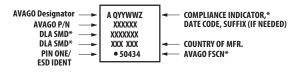
NOTE: DIMENSIONS IN MILLIMETERS (INCHES).

20 Terminal LCCC Surface Mount, 2 Channels



NOTE: DIMENSIONS IN MILLIMETERS (INCHES). SOLDER THICKNESS 0.127 (0.005) MAX.

Leaded Device Marking



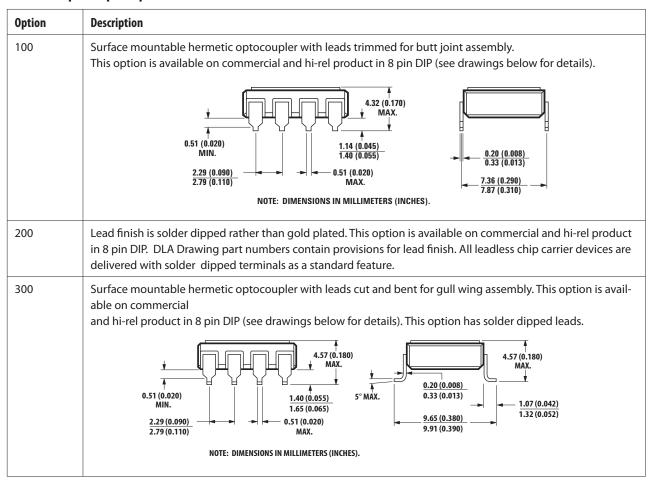
*QUALIFIED PARTS ONLY

Leadless Device Marking



*QUALIFIED PARTS ONLY

Hermetic Optocoupler Options

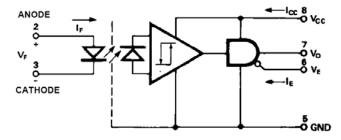


Note: Solder contains lead

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units
Storage Temperature Range	T _S	-65°	+150°	С
Operating Ambient Temperature	T _A	-55°	+125°	С
Junction Temperature	TJ		+175°	С
Case Temperature	T _C		+170°	С
Lead Solder Temperature (1.6 mm below seating plane)			260° for 10 s	С
Average Forward Current, each channel	I _{F AVG}		8	mA
Peak Input Current, each channel	I _{FPK}		20 [1]	mA
Reverse Input Voltage, each channel	V _R		3	V
Average Output Current, each channel	Io		15	mA
Supply Voltage	V _{CC}	0.0	20	V
Output Voltage, each channel	Vo	-0.3	20	V
Package Power Dissipation, each channel	P _D		200	mW
Single Channel Product Only		•		
Tri-State Enable Voltage	V _E	-0.3	20	V

8 Pin Ceramic DIP Single Channel Schematic



Note enable pin 6. An external 0.01 μ F to 0.1 μ F bypass capacitor is recommended between V_{CC} and ground for each package type.

ESD Classification

(MIL-STD-883, Method 3015)				
HCPL-5200/01/0K and HCPL-6230/31/3K	(▲), Class 1			
HCPL-5230/31/3K and HCPL-6250/51/5K	(Dot), Class 3			

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Power Supply Voltage	V _{CC}	4.5	20	V
Input Current, High Level, each channel	I _{FH}	2	8	mA
Input Voltage, Low Level, each channel	V _{FL}	0	0.8	V
Fan Out (TTL Load), each channel	N		4	
Single Channel Product Only				
High Level Enable Voltage	V _{EH}	2.0	20	V
Low Level Enable Voltage	V _{EL}	0	0.8	V

Electrical Characteristics

 $T_{A} = -55^{\circ}\text{C to } + 125^{\circ}\text{C}, 4.5 \text{ V} \leq \text{V}_{CC} \leq 20 \text{ V}, 2 \text{ mA} \leq \text{I}_{F(ON)} \leq 8 \text{ mA}, 0 \text{ V} \leq \text{V}_{F(OFF)} \leq 0.8 \text{ V}, \text{unless otherwise specified.}$

	Group A,		<u> </u>		Limits						
Parameter		Symbol	Sub-groups ^[11]	Test Condi	tions	Min.	Тур.*	Max.	Units	Fig.	Notes
	Output Voltage	V _{OL}	1, 2, 3	I _{OL} = 6.4 (4 TTL Lo			,,	0.5	V	1, 3	2
Logic High	n Output Voltage	V _{OH}	1, 2, 3	I _{OH} = -2.6 mA, (**V _{OH} = V _{CC} - 2.1 V)		2.4	**		V	2, 3	2
			NA	$I_{OH} = -0.32$			3.1				
Output Le Current (V	akage ′out > V _{CC})	Іонн	1, 2, 3	$V_0 = 5.5 \text{ V}$	I _F = 8 mA V _{CC} =			100	μА		2
				V _O = 20 V	4.5 V			500			
Logic Low	Single Channel	I _{CCL}	1, 2, 3	V _{CC} = 5.5 V	V _F = 0 V V _E =		4.5	6	mA		
Supply Current				V _{CC} = 20 V	Don't Care		5.3	7.5			
	Dual	1		V _{CC} = 5.5 V	$V_{F1} = V_{F2}$		9.0	12			
	Channel			V _{CC} = 20 V	= 0 V		10.6	15			
	Quad			$V_{CC} = 5.5 V$	$V_{F1} = V_{F2}$		14	24			
	Channel			V _{CC} = 20 V	$= V_{F3} = V_{F4} = 0 V$		17	30			
Logic	Single	I _{CCH}	1, 2, 3	V _{CC} = 5.5 V	$I_F = 8mA$		2.9	4.5	mA		
High Supply Current	Channel		V _{CC} = 20 V		3.3	6					
	Dual	1		V _{CC} = 5.5 V	$I_{F1} = I_{F2} =$		5.8	9			
	Channel			V _{CC} = 20 V	8mA		6.6	12			
	Quad	1		V _{CC} = 5.5 V	$I_{F1} = I_{F2} =$		9	18			
	Channel			V _{CC} = 20 V	$I_{F3} = I_{F4} = 8mA$		11	24			
Logic Low Output Cu	Short Circuit irrent	l _{OSL}	1, 2, 3	V _O = V _{CC} = 5.5 V	V _F = 0 V	20			mA		2, 3
				$V_O = V_{CC} = 20 \text{ V}$		35					
	Short Circuit	losh	1, 2, 3	V _{CC} = 5.5V	$I_F = 8 \text{ mA}$			-10	mA		2, 3
Output Cu	irrent			V _{CC} = 20 V	$V_0 = GND$			-25			
Input Forv	vard Voltage	V _F	1, 2, 3	I _F = 8 m	nΑ	1.0	1.3	1.8	V	4	2
Input Reve Breakdow		BV _R	1, 2, 3	I _R = 10	uΑ	3			V		2
Input-Out Leakage C	put Insulation Jurrent	I _{I-O}	1	$V_{I-O} = 1500 \text{ Vdc}, t = 5s,$ $RH \le 65\%, T_A = 25^{\circ}C$				1.0	μА		4, 5
Logic High Transient	n Common Mode Immunity	CM _H	9, 10, 11	$I_F = 2 \text{ mA}, V_{CM} = 50 V_{P-P}$		1000	10,000		V/µs	9	2, 6, 12
Logic Low Transient	Common Mode Immunity	CM _L	9, 10, 11	9, 10, 11 $I_F = 0 \text{ mA}, V_{CM} = 50 V_{P-P}$		1000	10,000		V/µs	9	2, 6, 12
Propagation	•	t _{PHL}	9, 10, 11				173	350	ns	5, 6	2, 7
Propagation		t _{PLH}	9, 10, 11				118	350	ns	5, 6	2, 7

Electrical Characteristics - Single Channel Product Only

 $T_{A} = -55^{\circ}\text{C to} + 125^{\circ}\text{C}, 4.5 \text{ V} \leq \text{V}_{CC} \leq 20 \text{ V}, 2 \text{ mA} \leq \text{I}_{F \text{ (ON)}} \leq 8 \text{ mA}, 0 \text{ V} \leq \text{V}_{F \text{(OFF)}} \leq 0.8 \text{ V}, 2.0 \text{ V} \leq \text{V}_{EH} \leq 20 \text{ V}, 0 \text{ V} \leq \text{V}_{EL} \leq 0.8 \text{ V}, \text{unless otherwise specified.}$

		Group A,				Limits				
Parameter	Symbol	Sub-groups ^[11]	Test Cor	Test Conditions		Тур.*	Max.	Units	Fig.	Notes
High Impedance State Output	l _{OZL}	1,2,3	V _O = 0.4 V	$V_{EN} = 2 V,$ $V_F = 0 V$			-20	μА		
Current	lozh	1,2,3	V _O = 2.4 V	V _{EN} = 2 V,			20	μΑ		
			V _O = 5.5 V	$I_F = 8 \text{ mA}$			100			
			V _O = 20 V				500			
Logic High Enable Voltage	V _{EH}	1, 2, 3			2.0			V		
Logic Low Enable Voltage	V _{EL}	1, 2, 3					0.8	V		
Logic High	I _{EH}	1, 2, 3	V _{EN} =	2.7 V			20	μА		
Enable Current			V _{EN} = 5.5 V				100			
			V _{EN} =	20 V		0.004	250			
Logic Low Enable Current	I _{EL}	1, 2, 3	V _{EN} =	0.4 V			-0.32	mA		

^{*}All typical values are at V_{CC} = 5 V, T_A = 25°C, $I_{F(ON)}$ = 5 mA unless otherwise specified.

Typical Characteristics

All typical values are at $T_A = 25$ °C, $V_{CC} = 5$ V, $I_{F(ON)} = 5$ mA unless otherwise specified.

Parameter	Symbol	Test Conditions	Тур.	Units	Fig.	Notes
Input Current Hysteresis	I _{HYS}	V _{CC} = 5 V	0.07	mA	3	2
Input Diode Temperature Coefficient	$\frac{\Delta V_F}{\Delta T_A}$	$I_F = 8 \text{ mA}$	-1.25	mV/°C		2
Resistance (Input-Output)	R _{I-O}	V _{I-O} = 500 Vdc	10 ¹³	Ω		2, 8
Capacitance (Input-Output)	C _{I-O}	f = 1 MHz	2.0	pF		2, 8
Input Capacitance	C _{IN}	V _F = 0 V, f = 1 MHz	20	pF		2, 10
Output Rise Time (10-90%)	t _r		45	ns	5, 7	2
Output Fall Time (90-10%)	t _f		10	ns	5, 7	2
Single Channel Product Only						
Output Enable Time to Logic High	t _{PZH}		30	ns	8	
Output Enable Time to Logic Low	t _{PZL}		30	ns	8	
Output Disable Time from Logic High	t _{PHZ}		45	ns	8	
Output Disable Time from Logic Low	t _{PLZ}		55	ns	8	
Multi-Channel Product Only						
Input-Input Insulation Leakage Current	I _{I-I}	RH \leq 65%, V _{I-I} = 500 V, t = 5 s	0.5	nA		9
Resistance (Input-Input)	R _{I-I}	V _{I-I} = 500 V	10 ¹³	Ω		9
Capacitance (Input-Input)	C _{I-I}	f = 1 MHz	1.5	pF		9

Notes:

- 1. Peak Forward Input Current pulse width < 50 μs at 1 KHz maximum repetition rate.
- 2. Each channel of a multichannel device.
- 3. Duration of output short circuit time not to exceed 10 ms.
- 4. All devices are considered two-terminal devices: measured between all input leads or terminals shorted together and all output leads or terminals shorted together.
- 5. This is a momentary withstand test, not an operating condition.
- CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state (V_O < 0.8 V). CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state (V_O > 2.0 V).
- 7. t_{PHL} propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3 V point on the leading edge of the output pulse. The t_{PLH} propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.
- 8. Measured between each input pair shorted together and all output connections for that channel shorted together.
- 9. Measured between adjacent input pairs shorted together for each multichannel device.
- 10. Zero-bias capacitance measured between the LED anode and cathode.
- 11. Standard parts receive 100% testing at 25°C (Subgroups 1 and 9). SMD, Class H and Class K parts receive 100% testing at 25, 125, and –55°C (Subgroups 1 and 9, 2 and 10, 3 and 11, respectively).
- 12. Parameters are tested as part of device initial characterization and after design and process changes. Parameters guaranteed to limits specified for all lots not specifically tested.

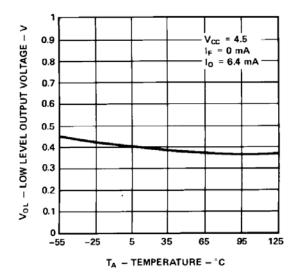


Figure 1. Typical Logic Low Output Voltage vs. Temperature.

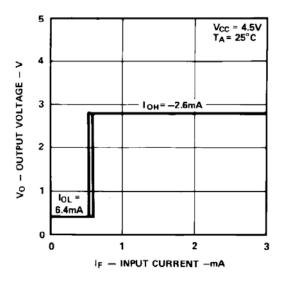


Figure 3. Output Voltage vs. Forward Input Current.

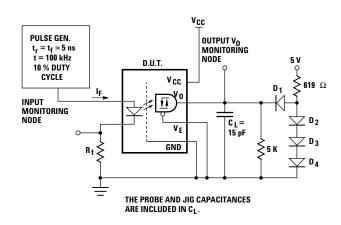


Figure 5. Test Circuit for t_{PLH} , t_{PHL} , t_{r} , and $t_{f\cdot}$

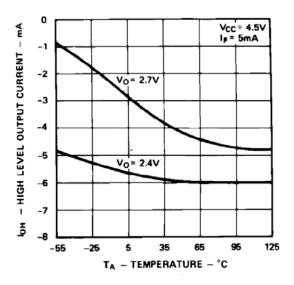


Figure 2. Typical Logic High Output Current vs. Temperature.

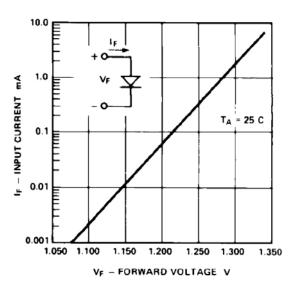
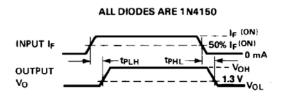


Figure 4. Typical Diode Input Forward Characteristic.



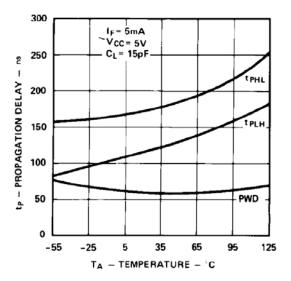


Figure 6. Typical Propagation Delay vs. Temperature.

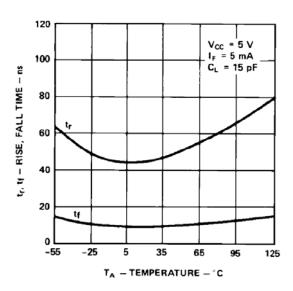
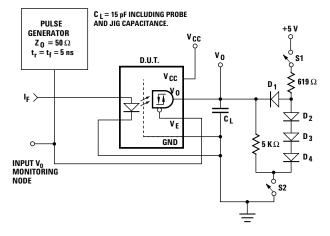
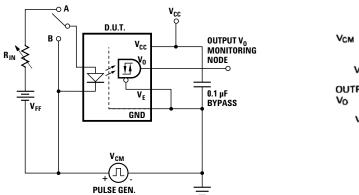


Figure 7. Typical Rise, Fall Time vs. Temperature.



D₁₋₄ ARE 1N916 OR 1N3064 INPUT ٧E tpLZ S1 AND S2 0.5V OUTPUT S1 CLOSED ٧o S2 OPEN tp<u>zh</u> 0.5V Vон OUTPUT 1.3V ≈1.5V Vo -0V S1 OPEN S1 AND S2 S2 CLOSED CLOSED

Figure 8. Test Circuit for tpHZ, tpZH, tpLZ, and tpZL.



OUTPUT SWITCH AT A: I_F = 2 mA

OUTPUT SWITCH AT B: I_F = 0 mA

Vol

*SEE NOTE 6.

Figure 9. Test Circuit for Common Mode Transient Immunity and Typical Waveforms.

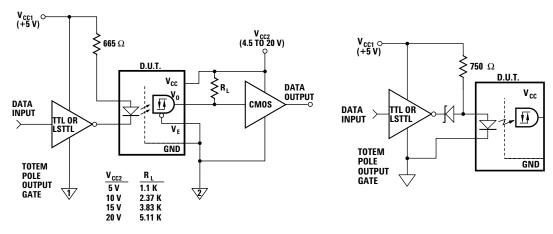


Figure 10. LSTTL to CMOS Interface Circuit.

Figure 11. Recommended LED Drive Circuit.

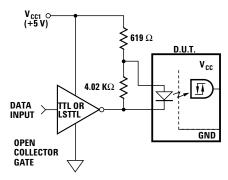
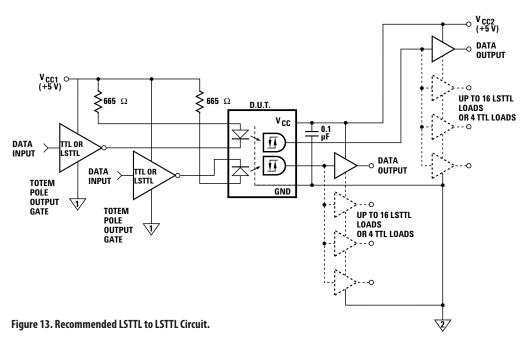


Figure 12. Series LED Drive with Open Collector Gate (4.02 $k\Omega$ Resistor Shunts I $_{OH}$ from the LED).



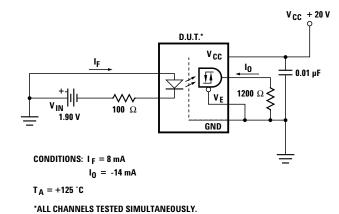


Figure 14. Single Channel Operating Circuit for Burn-in and Steady State Life Tests.

MIL-PRF-38534 Class H, Class K, and DLA SMD Test Program

Avago Technologies' Hi-Rel Optocouplers are in compliance with MIL-PRF-38534 Classes H and K. Class H and Class K devices are also in compliance with DLA drawings 5962-88768 and 5962-88769.

Testing consists of 100% screening and quality conformance inspection to MIL-PRF-38534.

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























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